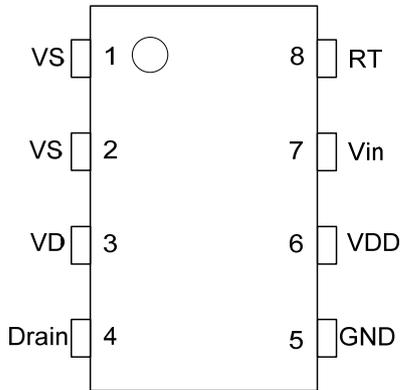


GENERAL INFORMATION

Pin Configuration

The OB2001x is offered in SOP8 package, shown as below.



Absolute Maximum Ratings

Parameter	Value
Vin pin	-0.6V to 7V
VDD pin	-0.6V to 7V
VD pin	-2.5V to 50V ^{Note2}
VS pin	-0.6V to 7V
RT pin	-0.6V to 7V
Drain pin	-0.6V to BVdss ^{Note3}
Min/Max Operating Junction Temperature T _J	-40 to 150 °C
Operating Temperature T _A	Ambient -20 to 85 °C
Min/Max Storage Temperature T _{stg}	-55 to 150 °C
Lead Temperature (Soldering, 10secs)	260 °C

Note1: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.

Note2: -2.5V applies to minimum duty cycle during normal operation only.

Note3: -0.6V is self-clamped

Ordering Information

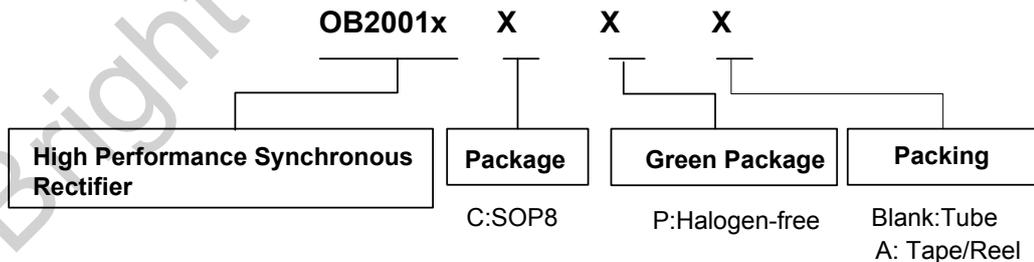
Part Number	Description
OB2001ZCP	SOP8, Halogen-free in Tube
OB2001ZCPA	SOP8, Halogen-free in T&R

Package Dissipation Rating

Package	R _{θJA} (°C/W)
SOP8	90

Recommended Operating Range

Symbol	Parameter	Min/Max
VDD	VDD Supply Voltage	4V to 5.5V



Marking Information

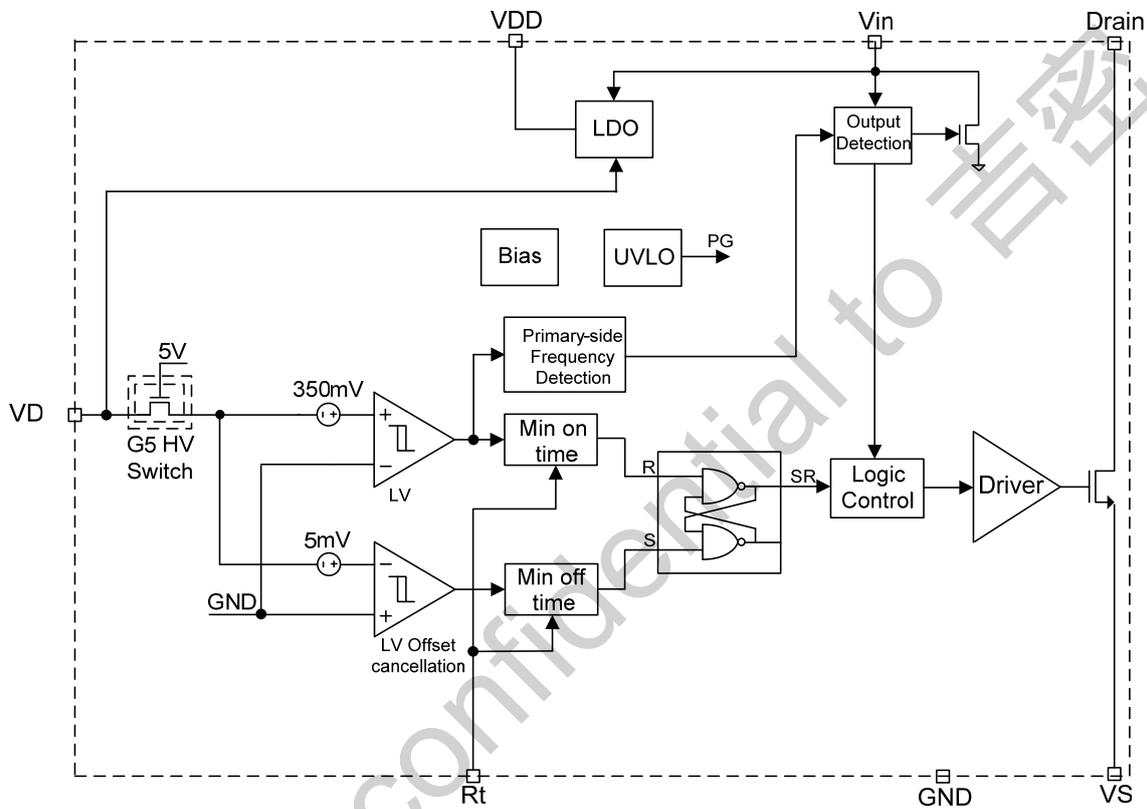


Y:Year Code
 WW:Week Code(01-52)
 ZZZ:Lot Code
 C:SOP8 Package
 P:Halogen-free Package
 S:Internal Code(Optional)

TERMINAL ASSIGNMENTS

Pin Name	I/O	Description
VS	I	This pin is connected to external n-channel MOSFET source
VD	I	This pin is connected to external n-channel MOSFET drain
Drain	I/O	SR Mosfet drain pin. This pin is connected to secondary-side winding of transformer
GND	P	Ground.
VDD	P	Power Supply
Vin	I	System output voltage detection
RT	O	Minimum on time control pin. A resistor is connected from this pin to GND

BLOCK DIAGRAM



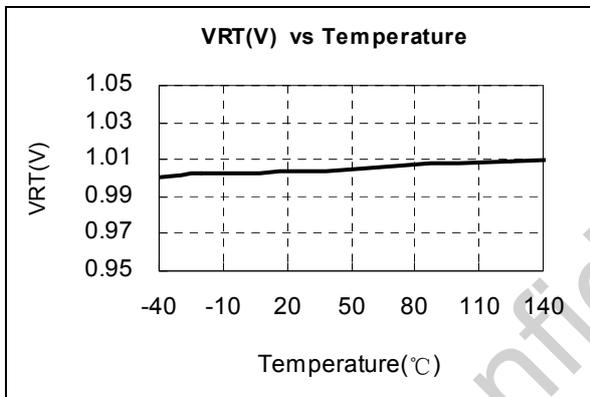
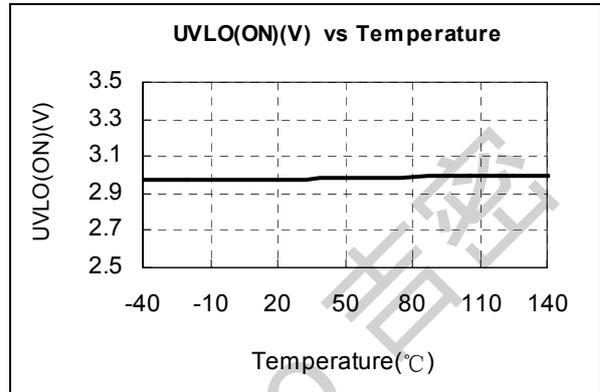
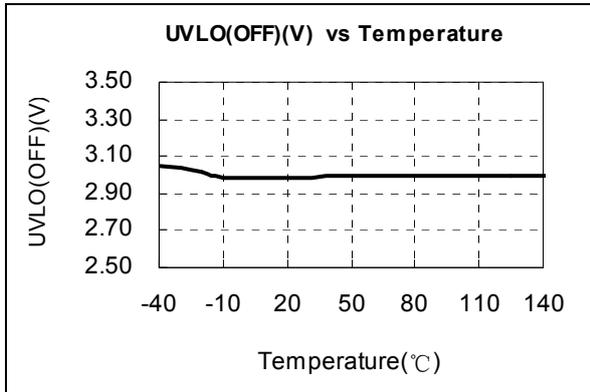
ELECTRICAL CHARACTERISTICS

(T_A = 25°C, VDD=5V, unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Typ.	Max	Unit
Supply Voltage (VDD)						
I_VDD_operation	Operation current	Frequency@VD=65KHz,VDD=5V		1.5	2.0	mA
		Frequency@VD=2KHz,VDD=5V		0.5	0.7	mA
VDD_regulation_mini	Minimum VDD regulation voltage			4.2		V
UVLO(ON)	VDD Under Voltage Lockout Entry		2.8	3.0	3.2	V
UVLO(OFF)	VDD Under Voltage Lockout Exit (Recovery)		2.9	3.1	3.3	V
VD Detection Section						
Vth_SR_act	SR MOSFET turn on threshold voltage detection at VD			-350		mV
Vth_SR_deact	SR MOSFET turn off threshold voltage detection at VD			-5		mV
Tdelay_on	SR MOSFET turn-on propagation delay				100	ns
Tdelay_off	SR MOSFET turn-off propagation delay				75	ns
T_minimum_on	SR MOSFET minimum on time	RT=25KΩ		1.9		us
RT Section						
Vrt	Voltage reference at RT pin		0.95	1	1.05	V
Overshoot Control Section						
Vin_High_clamp_1st	System output 1st overshoot clamp control trigger voltage at Vin with SR frequency lower than 7.5KHz			5.65		V
Vin_High_clamp_2nd	System output 2 nd overshoot clamp control trigger voltage at Vin			6.15		V
Ivin_High_clamp	System output overshoot clamp current at Vin			70		mA

SR Mosfet Section						
Parameter	BVdss(V) MOSFET Drain-Source Breakdown Voltage			Rds,on(mΩ) On resistance		
	Min	Typ.	Max	Min	Typ.	Max
Product						
OB2001Z	50				8	

CHARACTERIZATION PLOTS



Operation Description

OB2001x is a high performance and versatile synchronous rectifier. It can emulate the behavior of Schottky diode rectifier which directly reduces power dissipation of the traditional rectifiers and indirectly reduces primary-side loss due to compounding of efficiency gains.

Startup and under voltage lockout(UVLO)

OB2001x implements UVLO function during startup. When VDD rises above UVLO(off), the IC wakes up from under voltage lock out state and enter normal operation. When VDD drops below UVLO(on), the IC enter under voltage lock out state again and the SR gate is pulled low by 10K resistor on chip. In addition, there is a hysteresis window between UVLO(off) and UVLO(on) to make system work reliably.

Synchronization rectifier

OB2001x controls the turn-on and turn-off of synchronization rectifier MOSFET (SR MOSFET) by detection of drain-source voltage. When demagnetization of transformer starts, the secondary-side current will flow through the body diode of SR MOSFET and the voltage at the drain will drop to about -700mV. As soon as OB2001x detects this negative voltage, the driver voltage is pulled high to turn on the SR MOSFET after very short delay time about 100nS, refer to Fig.1. After the SR MOSFET is turned on, the drain voltage of SR MOSFET begins to rise based on its R_{dson} and secondary-side current. The drain voltage becomes higher with demagnetization going on. When the drain voltage rises above -5mV, the driver voltage will be pulled down to ground very quickly, refer to Fig.1

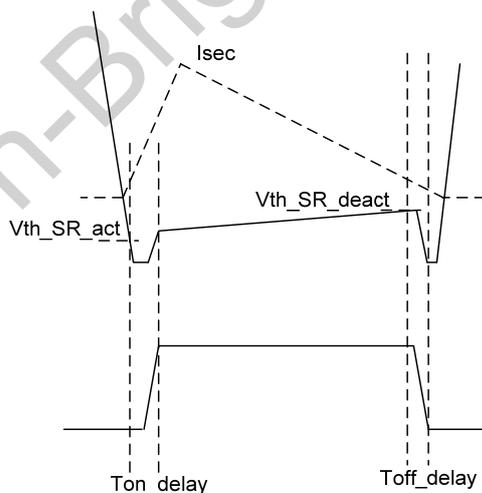


Fig.1 SR MOSFET turn-on and turn-off timing

Adjustable minimum on time

OB2001x offers adjustable minimum on time control. This timer can avoid effectively false turn-off due to high frequency interference caused by parasitic element at the start of secondary-side demagnetization.

$$T_{onmin} = 8 \cdot RT \cdot 10E(-11)$$

Adaptive minimum off time

At the end of demagnetization, SR MOSFET will be turn off. The remaining current will flow through body diode again, which may result in negative voltage (about -700mV) appears at drain and SR MOSFET will turn on again. In addition, the resonance oscillation between the magnetization inductance and parasitic capacitance after demagnetization may cause negative drain voltage. These may turn on SR MOSFET by mistake. To avoid above mis-turn-on of SR MOSFET, constant minimum off time can be used to screen it. But it may disturb SR MOSFET operation. For reliable SR operation, proprietary adaptive minimum off time control is implemented in OB2001x, which can guarantee reliable synchronous rectification operation in DCM, QR.

Output overshoot clamp

For poor system design, there is usually output overshoot during startup and load transient. To facilitate system design, OB2001x can detect output overshoot condition and prevent overshoot happen. When output voltage rises to meet the inner threshold, OB2001x will open a discharge path from Vin to ground to clamp the system output voltage, so the system output overshoot can be prevented.

PCB Layout Consideration

The following rules should be followed in OB2001Cx PCB Layout:

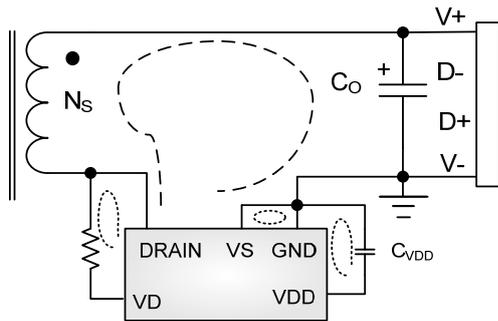
The Area of Power Loop: The area of the secondary current loop including the OB2001x and the output capacitor should be as small as possible to reduce EMI radiation. And the PCB trace must be wide and short for thermal consideration.

Ground Path: The VS pin should be shorted directly to the GND pin under the bottom of OB2001x before single point connected to the negative node of the output capacitor (Pink region as shows in Fig.3). This increases the copper area at the bottom of OB2001x for heat dissipation and reduce the impedance between VS pin and GND pin.

Bypass Capacitor: The bypass capacitor on VDD should be placed as close as possible to the VDD

pin. And the negative node of VDD capacitor should be connected directly to the GND pin (White region as shows in Fig.3).

VD pin and Drain pin: The resistor in the Fig.3 is recommended to be placed between the VD pin and the Drain pin for improving the ESD ability. The recommended value of the resistor is 10ohm with package type of 0805. No trace under this resistor is required (Green region as shows in Fig.3).



OB2001x

Fig.2 Proper Loop at the Secondary Side of the Flyback with OB2001x

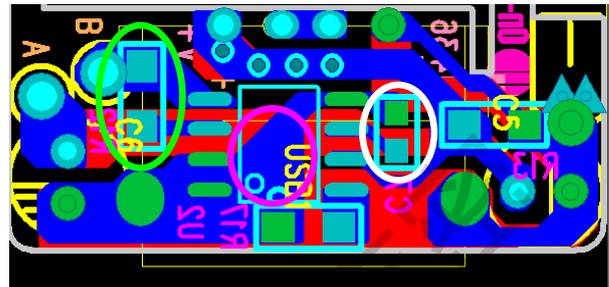
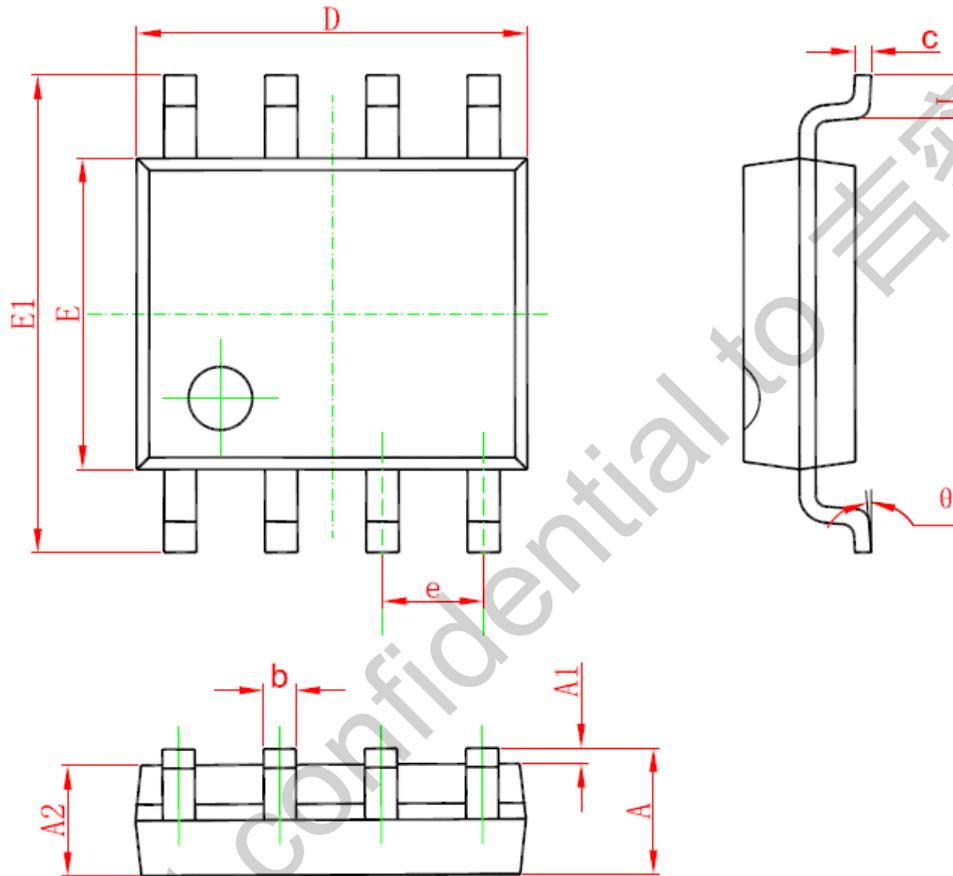


Fig.3 Recommend PCB Layout of OB2001x

PACKAGE MECHANICAL DATA
SOP8 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.050	0.250	0.002	0.010
A2	1.250	1.650	0.049	0.065
b	0.310	0.510	0.012	0.020
c	0.100	0.250	0.004	0.010
D	4.700	5.150	0.185	0.203
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270 (BSC)		0.050 (BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

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